NSN 5962-01-296-6836

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·····	
Body Length:	
0.960 inches	
Body Width:	
Between 0.220 inches and	0.310 inches
Body Height:	
Between 0.140 inches and	0.185 inches
Maximum Power Dissipat	tion Rating:
950.0 milliwatts	
Operating Tempurature R	lange:
-55.0/+125.0 degrees celsi	us
Storage Tempurature Rai	nge:
-65.0/+150.0 degrees celsi	us
Features Provided:	
Hermetically sealed and bu	Irn in and programmable and schottky and bipolar
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
12 input	
Case Outline Source And	Designator:
D-6 mil-m-38510	
Terminal Surface Treatme	ent:
Solder	
Voltage Rating And Type	Per Characteristic:
-0.5 volts power source an	id 7.0 volts power source
Time Rating Per Chacteri	stic:
55.00 nanoseconds propa	gation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard	d (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quan	tity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure	

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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